

Product Features

Features

- Stratum 3 Performance with 0.34 ppm (pk-pk) Holdover Stability Over Industrial Temperature Range (-40 °C to +85 °C)
- 3.0 V, 3.3 V and 5.0 V Options
- Low Phase Noise and Excellent G-Sens Performance (1.5 ppb/g)
- Tristate Function Available
- Available in Clipped Sine Wave or HCMOS

Applications

- Synchronous Ethernet Slave Clocks ITU-T G.8262 EEC Options 1 & 2
- Compliant to Stratum 3 GR-1244-Core & GR-253-Core
- SONET/SDH Network Timing
- Wireless Communications

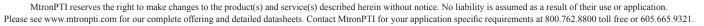
Product Description

MtronPTI's M615x Series TCXO and TCVCXO provide network and wireless engineers with low voltage, surface mount products with extremely tight stability over temperature and time. MtronPTI's unique approach to crystal compensation enables these devices to achieve full Stratum 3 compliance, including holdover stability over the industrial temperature range (-40 °C to +85 °C). Specially processed crystals enable the M615x to achieve consistent long-term stability and minimal frequency shift after reflow. This processing also achieves excellent g-sensitivity (1.5 ppb/g). The low phase noise (-155 dBc/Hz at 100 kHz offset) makes the M615x ideal for the design engineer working on all types of systems as the reference timing source.

Product Ordering Information

	M6151	2	S	т	S	N	00.0000 MHz	
Product Series								
M6150 = 5.0 V								
M6151 = 3.3 V								
M6152 = 3.0 V								
Temperature Range								
1: 0 °C to +70 °C	8: 0 °C to +50 °	°C						
2: -40 °C to +85 °C	F: -30 °C to +7	F: -30 °C to +75 °C						
6: -20 °C to +70 °C								
Stability			-					
S: ±4.6 ppm w/Holdov	er							
Output Type				-				
T: Voltage Controlled	With Tristate							
F: No Voltage Control	With Tristate							
Output Waveform					-			
C: HCMOS								
S: Clipped Sine Wave								
Package/Lead Config	gurations							
N: Leadless Ceramic ((10 pads)							
Frequency (custome	r specified)						-	
M615xSxxx - Custom	datasheets							

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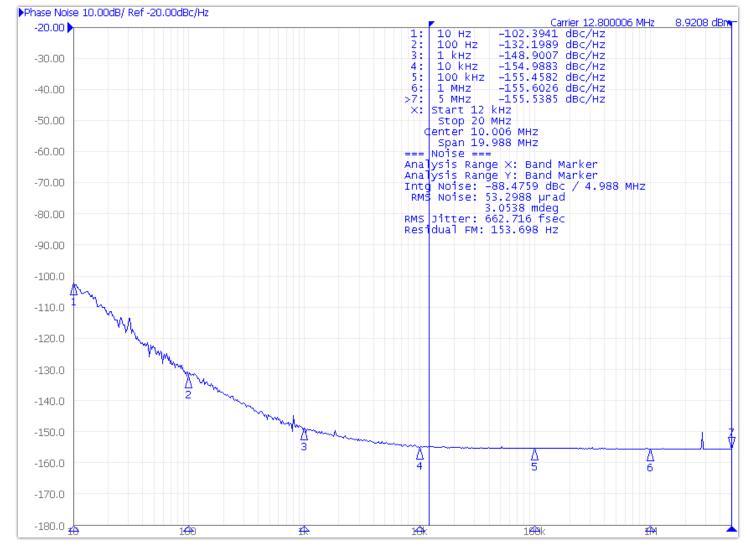


Performance Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions/Notes		
Frequency Range	Fo	8		38.88	MHz	Contact factory above 38.88 MHz.		
Initial Accuracy	F	-1.0		+1.0	ppm	@ +25 °C at time of shipment.		
Operating Temperature	T _A	(See C	Drdering Infor	mation)	°C			
Storage Temperature	T _{STG}	-55	-	+125	°C			
	510	Freq	uency Stab	ilities				
Stability vs Temperature	$\Delta F_T/F$			0.3	ppm	T _A = -40 °C to +85 °C (includes Hysteresis)		
						Ref GR1244CORE		
Stability vs Drift				40	ppb	After 24 hours at constant temperature.		
Free-Run Accuracy		-4.6		+4.6	ppm	Includes initial calibration @ +25 °C, deviation over temperature, supply voltage and load variations, reflow, hysteresis, and 20 year aging.		
Stability vs Supply Voltage	$\Delta F_{VDD}/F$		±0.02	±0.1	ppm	±5 % change in voltage.		
Stability vs Load	$\Delta F_{LOAD}/F$		±0.02	±0.1	ppm	±5 % change in load.		
		Supply	Voltage &	Current				
Supply Voltage (V _{DD}) Tolerance		-5.0		+5.0	%	(See Ordering Information)		
Supply Current (I _D)			2.0	3.0	mA	HCMOS output at 13 MHz		
(Reference to V_{DD} = 3.3 V)			3.0	4.0	mA	HCMOS output at 26 MHz		
			4.2	5.2	mA	HCMOS output at 38.88 MHz		
			1.3	2.0	mA	Clipped Sine Wave output at 13 MHz		
			1.7	2.7	mA	Clipped Sine Wave output at 26 MHz		
			2.3	3.5	mA	Clipped Sine Wave output at 38.88 MHz		
Output Logic Levels (HCMOS) Output Level (Clipped Sine Wave) Symmetry (Duty Cycle)			RF Output			• · ·		
Output Logic Levels	V _{OL}			20	% V _{DD}	$I_{OH}/I_{OL} = \pm 4 \text{ mA}, V_{DD} = +3.0 \text{ V}$		
(HCMOS)	V _{OH}	80			% V _{DD}	$I_{OH}/I_{OL} = \pm 4$ mA, $V_{DD} = +3.0$ V		
Output Level		1.0			V _{pk-pk}	F_{O} < 40 MHz		
(Clipped Sine Wave)		0.8			V _{pk-pk}	F _o > 40 MHz		
Symmetry (Duty Cycle)	t _{DC}	40	50	60	%	Ref. to 1/2 V _S . HCMOS Only		
Rise/Fall Time	t _R /t _F			6.5	ns	Ref. 10 % to 90 %. HCMOS only		
Output Load			15 pF			HCMOS Output		
			10 kΩ 10 p	F		Clipped Sine Wave Output		
Frequency Adjustment		±9.2			ppm	Over Control Voltage Range		
Control Voltage Range		0.3		2.7	V	For $V_{DD} = 3.0 V$		
		0.3		3.0	V	For $V_{DD} = 3.3 V$		
		0.5		4.5	V	For V_{DD} = 5.0 V		
Input Leakage Current		-50		+50	μA			
Input Resistance		100			kΩ			
Linearity				5	%			
Modulation Bandwidth		2 kHz						
		Ot	her Paramet	ters		-		
Tristate Function		70			$\% V_{DD}$	Output enabled. Logic "1" or "Open"		
				30	$\% V_{DD}$	Output disabled. Logic "0" or "GND"		
Tristate Leakage Current		-100		+100	μA	· · · · · · · · · · · · · · · · · · ·		
Phase Noise			-102		dBc/Hz	@ 10 Hz Offset		
(Typical 12.8 MHz HCMOS @ 3.3	V)		-132		dBc/Hz	@ 100 Hz Offset		
			-148		dBc/Hz	@ 1 kHz Offset		
			-154		dBc/Hz	@ 10 kHz Offset		
			-155		dBc/Hz	@ 100 kHz Offset		
Shock	MIL-STD-20	MIL-STD-202, Method 213, Condition C (100 g)						
Vibration Solderability Package			s 201 & 204 (0 Hz)		
Soldorability	EIAJ-STD-20	-			0 112 10 200	··,		
Solderability			and DID /D		o			
Package		5.0 mm x 7.0 mm, SMT and DIP (RoHS Compliant)						
Max Soldering Conditions	See solder	orofile						

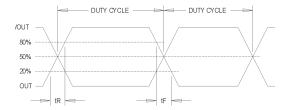


Phase Noise Plot



M615x 12.8 MHz Phase Noise

Output Waveform (HCMOS Output)



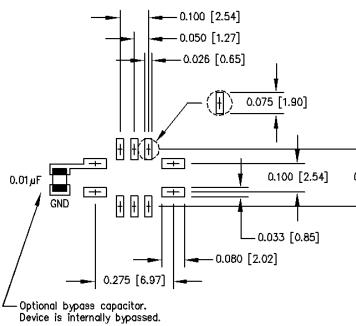


Product Dimension & Pinout Information

Pin Connections					
Function	Pad				
N/C - Do Not Connect	1				
N/C - Do Not Connect	2				
N/C - Do Not Connect	3				
Ground	4				
Output	5				
N/C - Do Not Connect	6				
N/C - Do Not Connect	7				
Tristate	8				
Supply Voltage (V _{DD})	9				
Control Voltage	10				

0.276 ±0.006 [7.00 ±0.15] 876 9 5 0.197 ±0.006 Line 1 [5.00 ±0.15] Line 2 10 23 1 All dimensions in inches [mm]. - Denotes Pin 1. 0.079 ±0.008 [2.00 ±0.20] ΗН 0.100 [2.54] 0.050 [1.27] 0.024 [0.60] 0.039 [1.00] Pin 1 0.035 [0.90] 7 7 7 7 0.100 [2.54] 0.031 [0.80] ſ

SUGGESTED SOLDER PAD LAYOUT





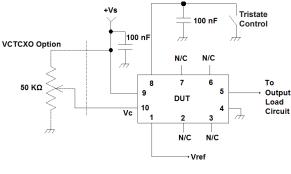
Handling Information

Although protection circuitry has been designed into the M615x oscillator, proper precautions should be taken to avoid exposure to electrostatic discharge (ESD) during handling and mounting. MtronPTI utilizes a human-body model (HBM) and a charged-device model (CDM) for ESD-susceptibility testing and protection design evaluation. ESD voltage thresholds are dependent on the circuit parameters used to define the mode. Although no industry-wide standard has been adopted for the CDM, a standard HBM (resistance = 1500 Ω , capacitance = 100 pF) is widely used and therefore can be used for comparison purposes. The HBM ESD threshold presented here was obtained using these circuit parameters.

Model	ESD Threshold, Minimum	Unit			
Human Body	1500*	V			
Charged Device	V				
* MIL-STD-833D, Method 3015, Class 1					

ATTENTION Static Sensitive Devices Handle only at Static Safe Work Stations

Typical Test Circuits

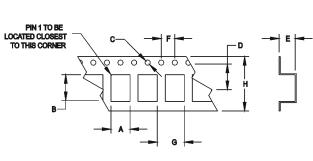


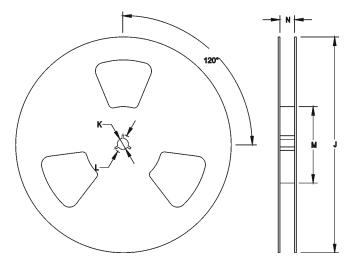
Test Circuit - N Package With Tristate



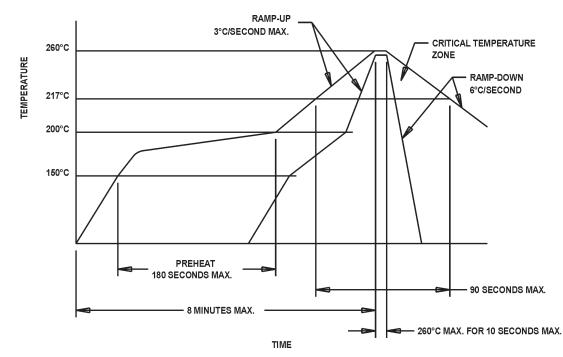
Tape & Reel Specifications

(all measurements are in mm)	Α	В	С	D	E	F	G	н	J	К	L	М	N
M615x	5.40	7.40	1.55	7.50	2.60	2.00	4.00	16.00	330	13.00	20.20	100	16.40





Standard Tape and Reel: 1000 parts per reel



Maximum Soldering Conditions

Note: Exceeding these limits may damage the device.

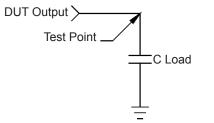


Quality Parameters

Environmental Specifications/Qualification Testing Performed						
Test	Test Method	Test Condition				
Electrical Characteristics	Internal Specification	Per Specification				
Frequency vs. Temperature	Internal Specification	Per Specification				
Mechanical Shock	MIL-STD-202, Method 213, C	100 g's				
Vibration	MIL-STD-202, Method 201-204	10 g's from 10-2000 Hz				
Thermal Cycle	MIL-STD-883, Method 1010, B	-55 Deg. C to +125 Deg. C, 15 minute Dwell, 10 cycles				
Aging	Internal Specification	168 Hours at 105 Degrees C				
Gross Leak	MIL-STD-202, Method 112	30 Second Immersion				
Fine Leak	MIL-STD-202, Method 112	Must meet 1x10-8				
Solderability	MIL-STD-883, Method 2003	8 Hour Steam Age – Must Exhibit 95% coverage				
Resistance to Solvents	MIL-STD-883, Method 2015	Three 1 minute soaks				
Physical Dimensions	MIL-STD-883, Method 2016	Per Specification				
Internal Visual	Internal Specification	Per Internal Specification				

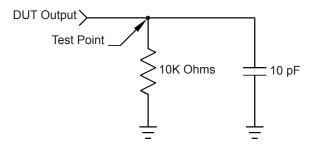
Load Circuit

Load Circuit #2 - HCMOS Output



Note: C Load includes probe and fixturing.

Load Circuit #7 - Clipped Sine Wave Output



For custom products or additional specifications contact our sales team at 800.762.8800 (toll free) or 605.665.9321

For more information on this product visit the MtronPTI website at www.mtronpti.com